

MUR105 THRU MUR160

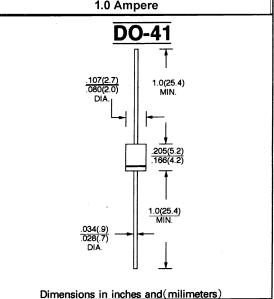
FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability
- * Ultra fast 25,50,75 Nanosecond Recovery Times

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V 0 rate flame retardant
- * Lead: and Mounting Surface Temperature for soldering Purposes 220°C Max for 10 Seconds 1/ 16" from case
- * Polarity: Color band denotes cathode end
- * Mounting Position: Any
- * Weight: 0.34 grams

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25℃ ambient temperature unless otherwise specified. Single phase, half wave, 60 H_Z, resistive or inductive load. For capacitive load, derate current by 20%

| TYPE NUMBER | SYMBOLS | MUR 105 | MUR 110 | MUR 115 | MUR 120 | MUR 130 | MUR 140 | MUR 160 | UNITS |
|---|----------------------------------|---|------------|------------|------------|------------|------------|--------------------------|-------|
| Maximum Recurrent Peak Reverse Voltage | V _{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | |
| Maximum RMS Voltage | V _{RMS} | 35 | 70 | 105 | 140 | 210 | 280 | 420 | v |
| Maximum D. C Blocking Voltage | V _{DC} | 105 | 100 | 150 | 200 | 300 | 400 | 600 | ٧ |
| Maximum Average Forward Rectified Current Seefig. 1 | I _{F(AV)} | 1.0 @ T _A = 110℃ 1.0 @ T _A = 100℃ | | | | | Α | | |
| Peak Forward Surge Current, 8.3 ms single half sine – wave superimposed on rated load(JEDEC method) | I _{FSM} | 35 | | | | | | Α | |
| Maximum Instantaneous Forward Voltage 1.0A(Note 1) | V _F | 0.975 1.25 | | | | | V | | |
| Maximum D. C Reverse Current @T _A = 25°C At Rated D. C Blocking Voltage @T _A = 100°C | I _R | 2.0 50 | | | 5.0 150 | | | μ Α μ Α | |
| Maximum Reverse Recovery Time(Note 2) | T _{RR} | 25 50 | | | | nS | | | |
| Typical Junction Capacitance (Note 3) | CJ | 25 | | | | | | pF | |
| Typical Thermal Resistance Junction to Ambient(Note 4) | R _{OJA} | 50 | | | | | | %W | |
| Operating and Storage Temperature Range | T _J ,T _{STG} | - 65 to + 150 | | | | | | °C | |

NOTES: 1. Pulse test: $t_p = 300\mu s$, duty cycle $\leq 2\%$

- 2. Reverse Recovery Test Conditions: $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$.
- 3. Measured at 1 MHz and applied reverse voltage of 4.0V D.C.
- 4. Lead length = 3/8" on P.C. Board with 1.5" × 1.5" copper surface



RATINGS AND CHARACTERISTIC CURVES

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FIG. 1 - FORWARD CURRENT DERATING CURVE

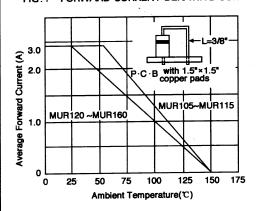


FIG. 2 - TYPICAL REVERSE LEAKAGE CHARCTERISTICS

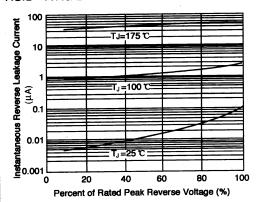


FIG.3 - TYPICAL JUNCTION CAPACITANCE

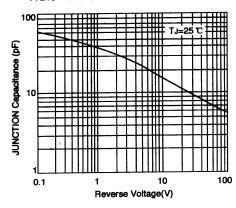


FIG.4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

